



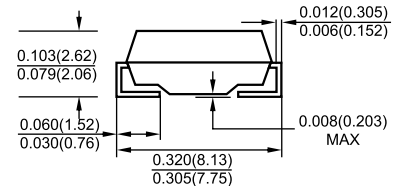
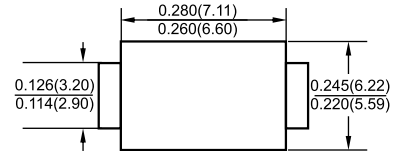
Features

- ✧ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ✧ For surface mounted applications
- ✧ Metal silicon junction, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ Built-in strain relief, ideal for automated placement
- ✧ High forward surge current capability
- ✧ High temperature soldering guaranteed: 250°C/10 seconds at terminals

Mechanical Data

- ✧ **Case:** JEDEC DO-214AB molded plastic body
- ✧ **Terminals:** leads solderable per MIL-STD-750, Method 2026
- ✧ **Polarity:** Color band denotes cathode end
- ✧ **Mounting Position:** Any
- ✧ **Weight:** 0.005 ounce, 0.138 grams

SMC/DO-214AB



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	SS3200	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	200	VOLTS
Maximum RMS voltage	V_{RMS}	140	VOLTS
Maximum DC blocking voltage	V_{DC}	200	VOLTS
Maximum average forward rectified current at T_L (see fig. 1)	$I_{(AV)}$	3.0	Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	100.0	Amps
Maximum instantaneous forward voltage at 3.0A	V_F	0.84	Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	1.0 10	mA
Typical junction capacitance (NOTE 1)	C_J	300	pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	62.0	$^\circ\text{C/W}$
Operating junction temperature range	T_J	-65 to +150	$^\circ\text{C}$
Storage temperature range	T_{STG}	-65 to +150	$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

RATINGS AND CHARACTERISTIC CURVES SS3200

